

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
100V	2.1 Ω @10V	0.17A
	2.2 Ω @4.5V	

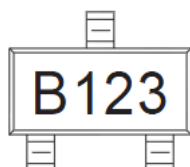
Feature

- Surface Mount Package
- High Density Cell Design for Extremely Low $R_{DS(ON)}$
- Voltage Controlled Small Signal Switch
- Rugged and Reliable

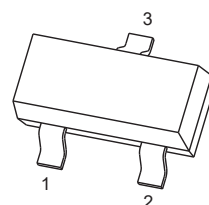
Application

- Small Servo Motor Controls
- Power MOSFET Gate Drivers
- Switching Application

MARKING:

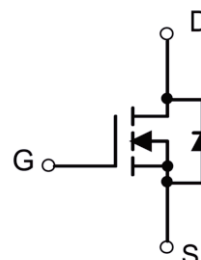


SOT-23



1. GATE
2. SOURCE
3. DRAIN

Schematic diagram



ABSOLUTE MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	100	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	0.17	A
Pulsed Drain Current ($t_p=10\mu\text{s}$)	I_{DM}	0.68	A
Power Dissipation	P_D	0.35	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	357	$^{\circ}\text{C/W}$
Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-55~ +150	$^{\circ}\text{C}$

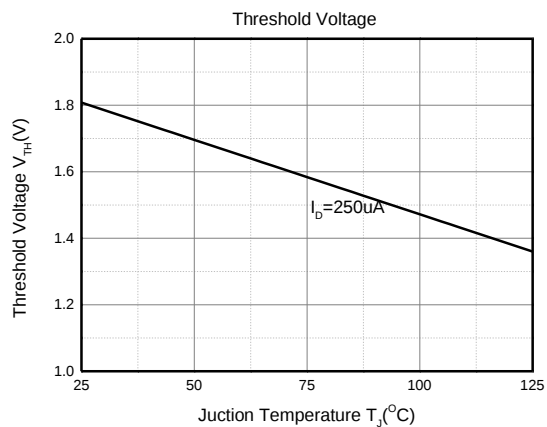
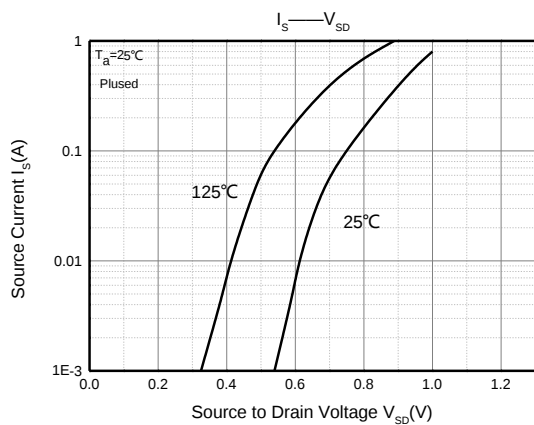
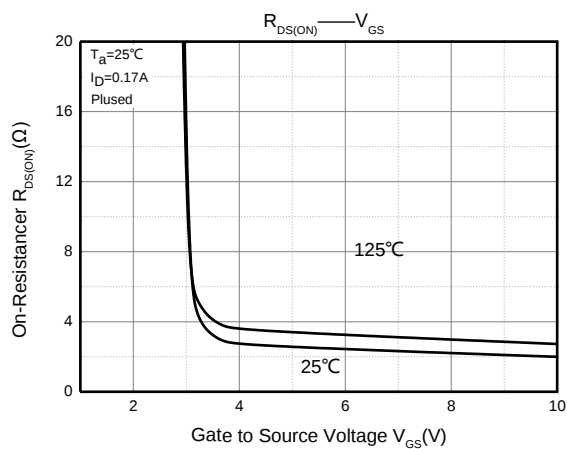
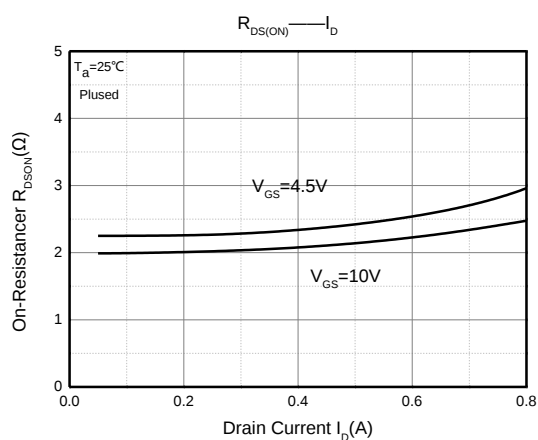
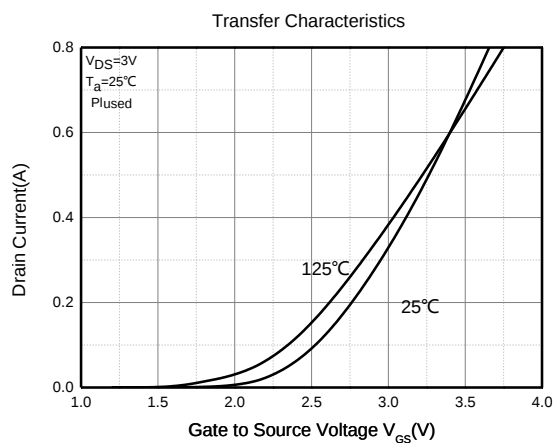
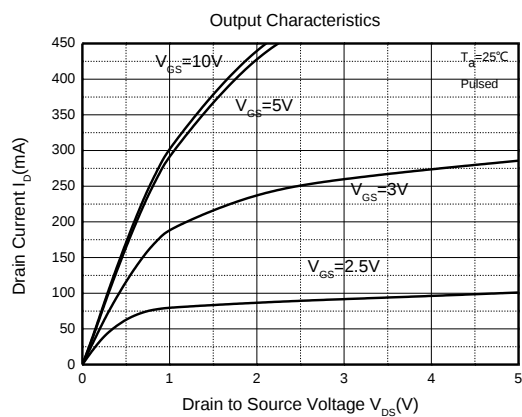
MOSFET ELECTRICAL CHARACTERISTICS($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Type	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =250μA	100			V
Zero gate voltage drain current	I _{DSS}	V _{DS} =80V,V _{GS} = 0V			1	μA
Gate-body leakage current	I _{GSS}	V _{GS} =±20V, V _{DS} = 0V			±100	nA
Gate threshold voltage ¹	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	1	1.8	3	V
Drain-source on-resistance ¹	R _{DS(on)}	V _{GS} =10V, I _D =0.17A		2.1	4.5	Ω
		V _{GS} =4.5V, I _D =0.17A		2.2	6.0	
Forward tranconductance ¹	g _{FS}	V _{DS} =10V, I _D =0.17A		0.45		S
Diode forward voltage ¹	V _{SD}	I _S =0.17A, V _{GS} = 0V		0.8	1.3	V
Dynamic characteristics						
Input Capacitance	C _{iss}	V _{DS} =25V,V _{GS} =0V,f =1MHz		32		pF
Output Capacitance	C _{oss}			8		
Reverse Transfer Capacitance	C _{rss}			2.6		
Switching Characteristics						
Turn-on delay time	t _{d(on)}	V _{GS} =10V,V _{DD} =30V, I _D =0.28A,R _{GEN} =50Ω		7		ns
Turn-on rise time	t _r			6		
Turn-off delay time	t _{d(off)}			10		
Turn-off fall time	t _f			9		
Total Gate Charge	Q _g	V _{DS} =10V,I _D =0.22A,V _{GS} =10V		1.5		nC
Gate-Source Charge	Q _{gs}			0.16		
Gate-Drain Charge	Q _{gd}			0.2		

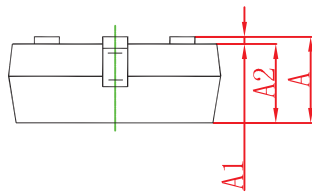
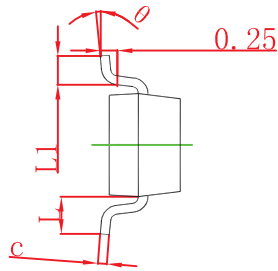
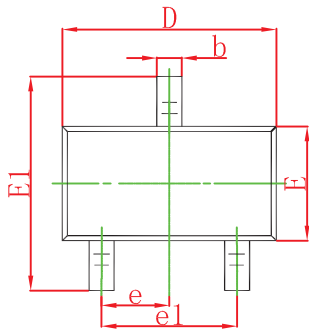
Notes :

1. Pulse Test : Pulse width=300 μs , duty cycle $\leq 2\%$.

Typical Characteristics



SOT-23 Package Information

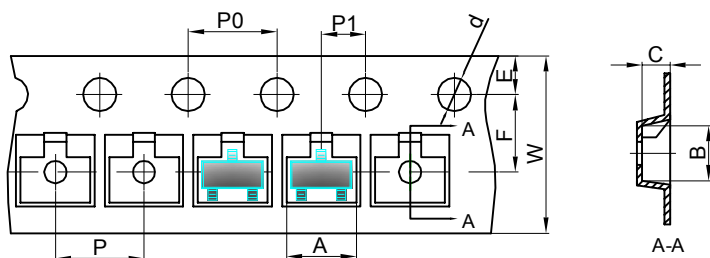


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

SOT-23 Tape and Reel

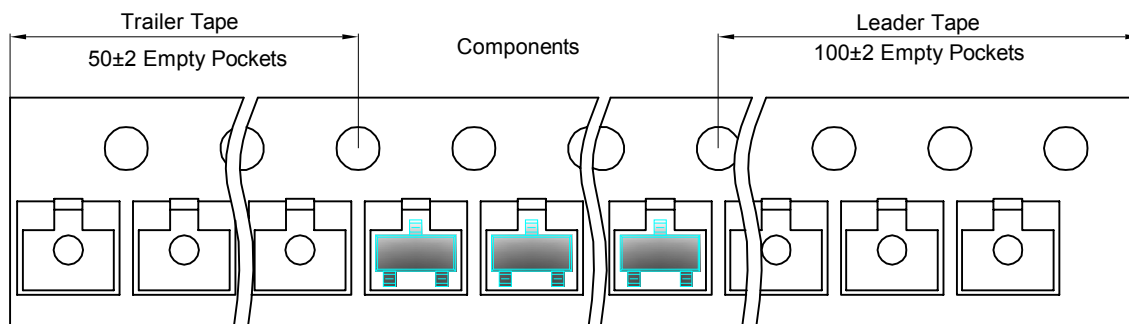
SOT-23 Tape and reel

SOT-23 Embossed Carrier Tape

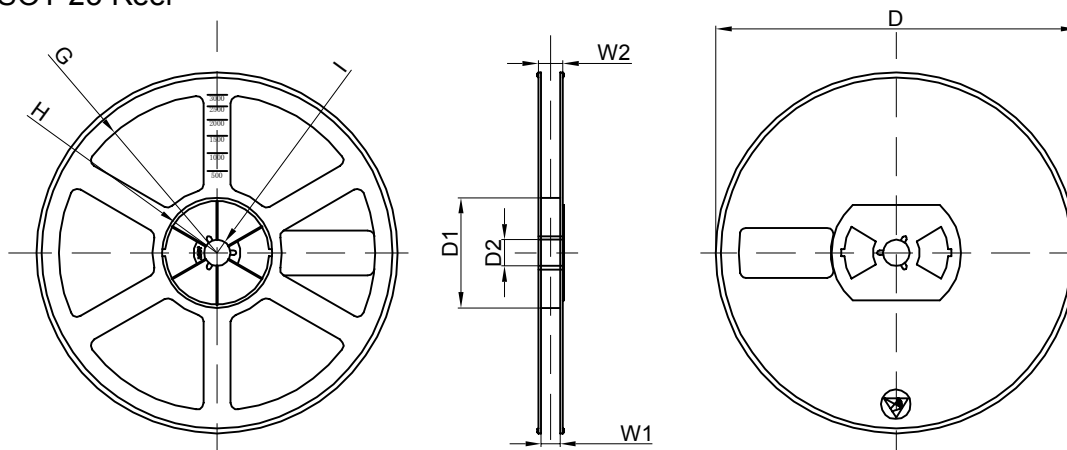


Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-23 Tape Leader and Trailer



SOT-23 Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7"Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	